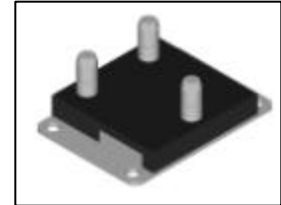


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**BRIDGE RECTIFIER ASSEMBLY**



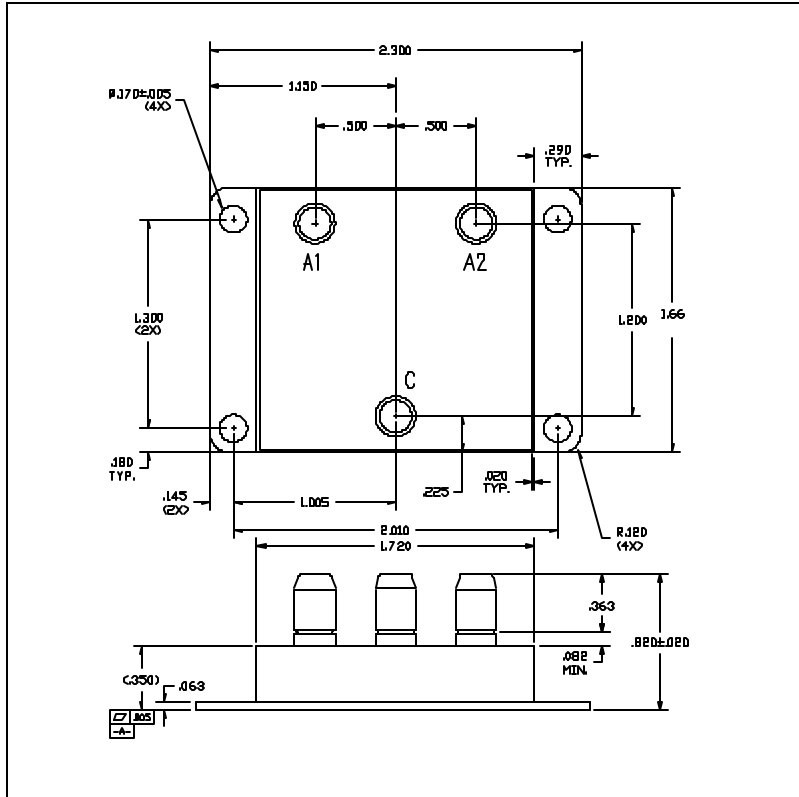
- High current – up to 120 Amps
- Various voltages – up to 1000 Volts
- Low thermal resistance
- Lowest trr available is 30nsec.

**MAX. RATINGS / ELECTRICAL CHARACTERISTICS** All ratings are at  $T_A = 25^\circ\text{C}$  unless otherwise specified.

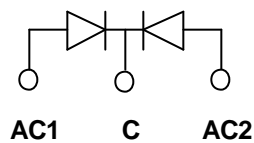
RATING	CONDITIONS	MIN	TYP	MAX	UNIT
Peak Inverse Voltage (PIV)	-	-	-	800	Vdc
Average DC Output Current ( $T_C = \text{Case Temp}$ ) ( $I_o$ )	$T_C = 55^\circ\text{C}$ $T_C = 100^\circ\text{C}$	-	-	160	Amps
Peak Single Cycle Surge Current ( $I_{FSM}$ )	$t_p = 8.3$ ms Single Half Cycle Sine Wave, Superimposed On Rated Load	-	-	200	Amps(pk)
Peak Recurring Surge Current (non-repetitive ( $I_{FRM}$ ))	$T_A = 25^\circ\text{C}$	-	-	500	Amps
Storage Temp. ( $T_{stg}$ )	-	-55	-	175	$^\circ\text{C}$
Operating Temp. ( $T_{op}$ )	-	-55	-	100	
Maximum Forward Voltage Per Leg ( $V_f$ )	$I_f = \_A\text{dc}$ (300 $\mu\text{sec}$ pulse, duty cycle < 2%)	-	-		Volts
Maximum Instantaneous Reverse Current At Rated (PIV)	$T_A = 25^\circ\text{C}$ $T_A = 100^\circ\text{C}$	-	-	100	$\mu\text{Amps}$
Reverse Recovery Time ( $t_{rr}$ )	$I_f = 0.5\text{A}$ , $I_r = 1.0\text{A}$ ; $I_{rr} = 0.25\text{A}$  Measured on discrete rectifiers prior to assembly.	-	-	120	nsec
Max. Thermal Resistance ( $R_{\theta JC}$ )	-	-	-	0.25	$^\circ\text{C/W}$

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**MECHANICAL DIMENSIONS: In Inches / mm**



**SCHEMATIC**



**TECHNICAL DATA**

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